





74LV367

FEATURES

- Optimized for Low Voltage applications: 1.0 to 3.6V
- Accepts TTL input levels between V_{CC} = 2.7V and V_{CC} = 3.6V
- Typical V_{OLP} (output ground bounce) < 0.8V @ V_{CC} = 3.3V, $T_{amb} = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) > 2V @ V_{CC} = 3.3V, T_{amb} = 25°C
- Non-inverting outputs
- Output capability: bus driver
- I_{CC} category: MSI

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

DESCRIPTION

The 74LV367 is a low-voltage CMOS device and is pin and function compatible 74HC/HCT367.

The 74LV367 is a hex non-inverting buffer/line driver with 3-State outputs. The 3-State outputs (nY) are controlled by the output enable inputs $(1\overline{OE}, 2\overline{OE})$.

A HIGH on nOE, causes the outputs to assume a high impedance OFF-state.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nA to nY	$\begin{array}{l} C_L = 15 p F \\ V_{CC} = 3.3 V \end{array}$	8	ns
Cl	Input capacitance		3.5	pF
C _{PD}	Power dissipation capacitance per buffer	Notes 1 and 2	30	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in $\mu W)$ 1. CPD is used to determine the dynamic power dissipation (PD in p $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_0)$ where: $f_i = input frequency in MHz; C_L = output load capacitance in pF;$ $f_o = output frequency in MHz; V_{CC} = supply voltage in V;$ $\Sigma (C_L \times V_{CC}^2 \times f_0) = sum of the outputs.$ 2. The condition is V_I = GND to V_{CC}

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
16-Pin Plastic DIL	–40°C to +125°C	74LV367 N	74LV367 N	SOT38-4
16-Pin Plastic SO	–40°C to +125°C	74LV367 D	74LV367 D	SOT109-1
16-Pin Plastic SSOP Type II	–40°C to +125°C	74LV367 DB	74LV367 DB	SOT338-1
16-Pin Plastic TSSOP Type I	–40°C to +125°C	74LV367 PW	74LV367PW DH	SOT403-1

PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1, 15	10E, 20E	Output enable inputs (active-LOW)
2, 4, 6, 10, 12, 14	1A to 6A	Data inputs
3, 5, 7, 9, 11, 13	1Y to 6Y	Data outputs
8	GND	Ground (0V)
16	V _{CC}	Positive supply voltage

FUNCTION TABLE

INPUTS		OUTPUT
nOE	nA	nY
L	L	L
L	Н	Н
Н	Х	Z

H = HIGH voltage level

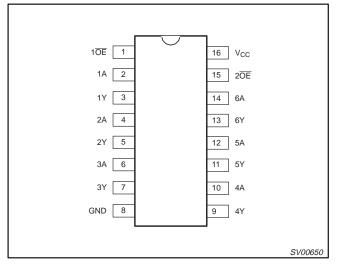
L = LOW voltage level

X = Don't care

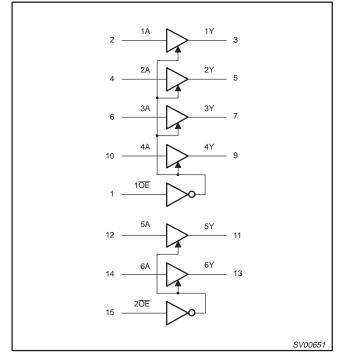
Z = High impedance OFF-state

74LV367

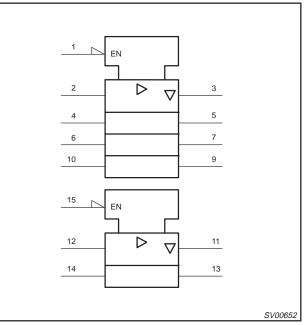
PIN CONFIGURATION



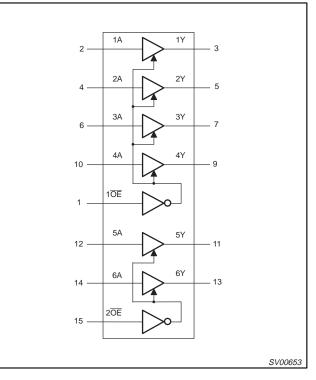
LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTIONAL DIAGRAM



74LV367

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	3.6	V
VI	Input voltage		0	-	V _{CC}	V
V _O	Output voltage		0	-	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	40 40		+85 +125	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.0V \text{ to } 2.0V$ $V_{CC} = 2.0V \text{ to } 2.7V$ $V_{CC} = 2.7V \text{ to } 3.6V$			500 200 100	ns/V

NOTE:

1. The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 3.6V.

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
±I _{IK}	DC input diode current	$V_{\rm I}$ < –0.5 or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5V	20	mA
±ΙΟΚ	DC output diode current	$V_{\rm O}$ < –0.5 or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5V	50	mA
±ΙΟ	DC output source or sink current – bus driver outputs	$-0.5V < V_O < V_{CC} + 0.5V$	35	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with -bus driver outputs		70	mA
T _{stg}	Storage temperature range		–65 to +150	°C
Power dissipation per package -plastic DIL -plastic mini-pack (SO) -plastic shrink mini-pack (SSOP and TSSOP)		for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

74LV367

DC CHARACTERISTICS FOR THE LV FAMILY

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

			LIMITS						
SYMBOL PARAMETER	TEST CONDITIONS	-40°C to +85°C			-40°C to +125°C		UNIT		
			MIN	TYP ¹	MAX	MIN	MAX		
		$V_{CC} = 1.2V$	0.9			0.9			
V_{IH}	HIGH level Input voltage	$V_{CC} = 2.0 V$	1.4			1.4		V	
		V _{CC} = 2.7 to 3.6V	2.0			2.0			
		$V_{CC} = 1.2V$			0.3		0.3		
V_{IL}	LOW level Input voltage	$V_{CC} = 2.0 V$			0.6		0.6	V	
		V _{CC} = 2.7 to 3.6V			0.8		0.8		
		V_{CC} = 1.2V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A		1.2					
Maria	HIGH level output	V_{CC} = 2.0V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A	1.8	2.0		1.8		v	
VOH	V _{OH} voltage; all outputs	V_{CC} = 2.7V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A	2.5	2.7		2.5			
		V_{CC} = 3.0V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A	2.8	3.0		2.8			
V _{OH}	HIGH level output voltage; BUS driver outputs	V_{CC} = 3.0V; V_I = V_{IH} or $V_{IL;}$ – I_O = 8mA	2.40	2.82		2.20		V	
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0					
M	LOW level output	$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0	0.2		0.2	1	
V _{OL}	voltage; all outputs	V_{CC} = 2.7V; V_I = V_{IH} or $V_{IL;} I_O$ = 100 μ A		0	0.2		0.2		
		V_{CC} = 3.0V; V_I = V_{IH} or $V_{IL;} I_O$ = 100 μ A		0	0.2		0.2		
V _{OL}	LOW level output voltage; BUS driver outputs	V_{CC} = 3.0V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 8mA		0.20	0.40		0.50	V	
I _I	Input leakage current	V_{CC} = 3.6V; V_{I} = V_{CC} or GND			1.0		1.0	μΑ	
I _{OZ}	3-State output OFF-state current	$V_{CC} = 3.6V; V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or } GND$			5		10	μΑ	
I _{CC}	Quiescent supply current; MSI	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}; I_O = 0$			20.0		160	μΑ	
ΔI_{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V$ to 3.6V; $V_{I} = V_{CC} - 0.6V$			500		850	μA	

NOTE:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$.

74LV367

AC CHARACTERISTICS

 $\text{GND} = \text{0V}; \ t_{\text{f}} = t_{\text{f}} \leq 2.5 \text{ns}; \ \text{C}_{\text{L}} = 50 \text{pF}; \ \text{R}_{\text{L}} = 1 \text{K} \Omega$

			CONDITION						
SYMBOL	SYMBOL PARAMETER		CONDITION	–40 to +85 °C			−40 to +125 °C		UNIT
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX	
			1.2	-	50	-	-	-	
	Propagation delay	Figure 1	2.0	-	17	32	-	39	
t _{PHL} /t _{PLH}	nA to nY	Figure 1	2.7	-	13	24	-	29	ns
			3.0 to 3.6	-	10 ²	19	-	23	
	3-State output enable time	Figure 2	1.2	-	80	-	-	-	ns
			2.0	-	27	51	-	60	
t _{PZH} /t _{PZL}	nOE to nY		2.7	-	20	38	-	44	
			3.0 to 3.6	-	15 ²	30	-	36	
	3-State output disable time		1.2	-	90	-	-	-	
		Figure 0	2.0	-	32	59	-	70	ns
t _{PHZ} /t _{PLZ}	$n\overline{OE}$ to nY	Figure 2	2.7	-	24	44	-	52	
			3.0 to 3.6	-	19 ²	36	-	42	

NOTES:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$ 2. Typical values are measured at $V_{CC} = 3.3V$

AC WAVEFORMS

 V_M = 1.5V at $V_{CC} \ge 2.7V$ V_M = 0.5V * V_{CC} at $V_{CC} < 2.7V$ V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load. $\begin{array}{l} \text{Output load.} \\ \text{V}_X = \text{V}_{OL} + 0.3\text{V} \text{ at } \text{V}_{CC} \geq 2.7\text{V} \\ \text{V}_X = \text{V}_{OL} \ 0.1\text{V}_{CC} \text{ at } \text{V}_{CC} < 2.7\text{V} \\ \text{V}_Y = \text{V}_{OH} - 0.3\text{V} \text{ at } \text{V}_{CC} \geq 2.7\text{V} \\ \text{V}_Y = \text{V}_{OH} - 0.1\text{V}_{CC} \text{ at } \text{V}_{CC} < 2.7\text{V} \end{array}$

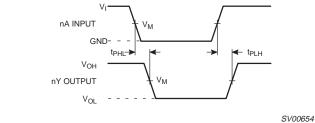


Figure 1. Input (nA) to output (nY) propagation delays.

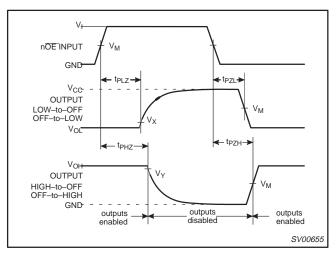


Figure 2. 3-State enable and disable times.

74LV367

TEST CIRCUIT

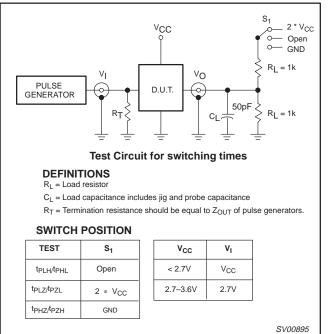
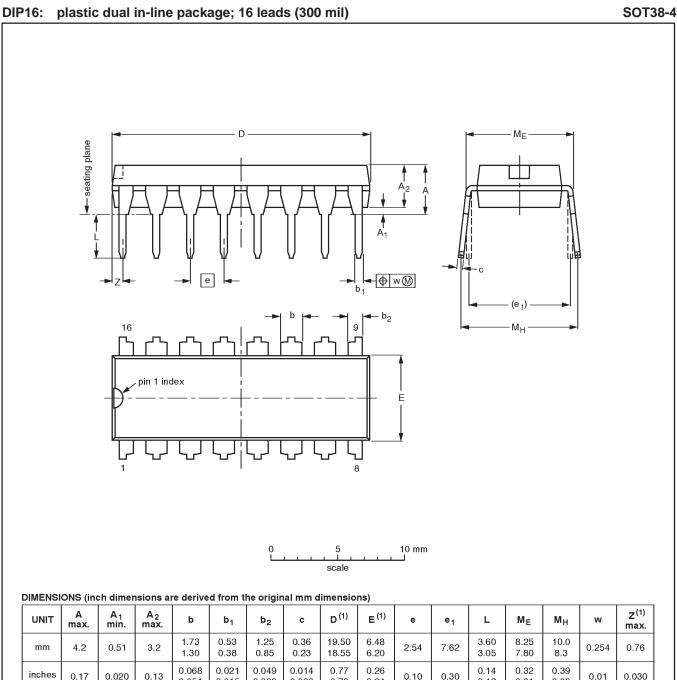


Figure 3. Load circuitry for switching times.

0.01

0.030



Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

0.051

0.015

0.033

0.009

0.020

0.17

0.13

OUTLINE REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT38-4						-92-11-17 95-01-14

0.73

0.24

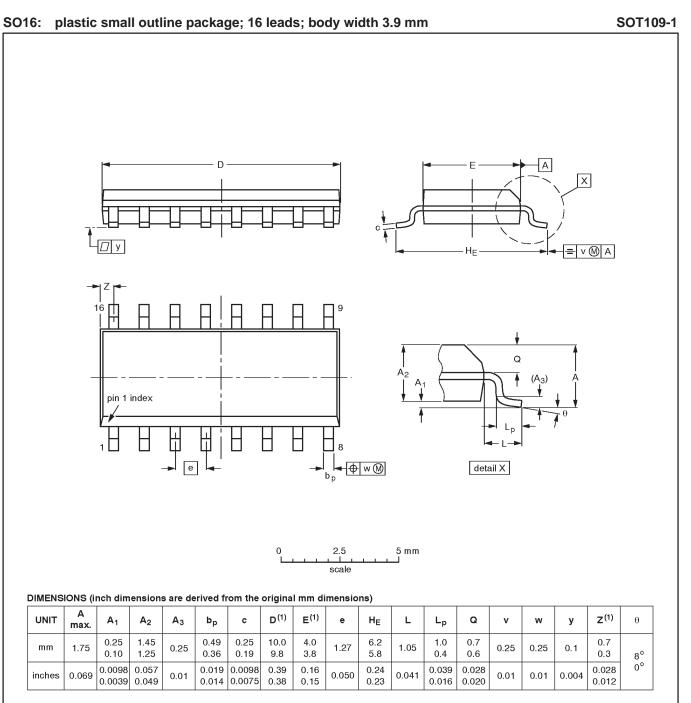
0.10

0.30

0.12

0.31

0.33



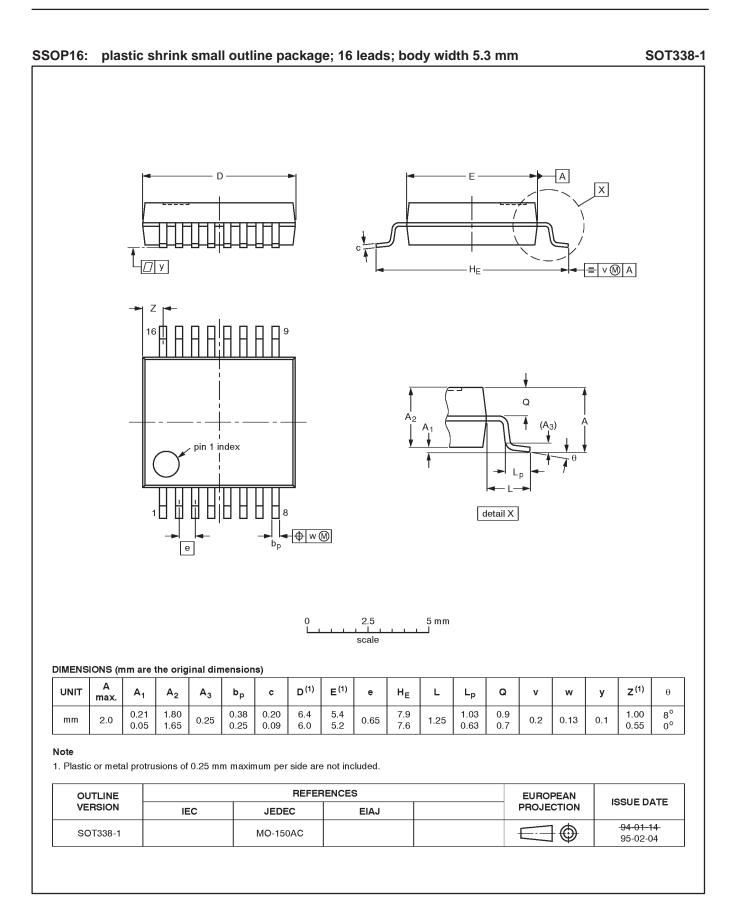
Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

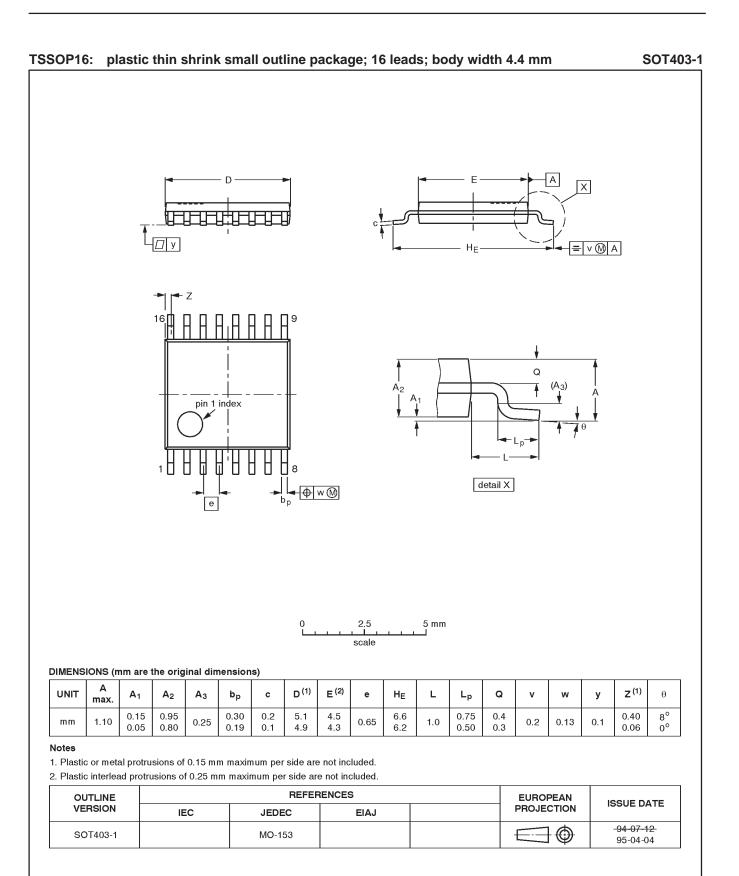
OUTLINE	OUTLINE REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT109-1	076E07S	MS-012AC				91-08-13 95-01-23	

74LV367

74LV367



74LV367



74LV367

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